Thyristor Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Metal

**Overall Length:** 

2.500 inches

# Mounting Facility Quantity:

1

## Electrode Internally-electrically Connected To Case:

Anode

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 1.031 inches and 1.063 inches

#### Thread Size:

0.500 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

800.0 breakover voltage, dc

## Current Rating Per Characteristic:

110.00 amperes drain current

## Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector preset

## **Thread Series Designator:**

Unf

## **Terminal Type And Quantity:**

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

## Fiig:

A110a0